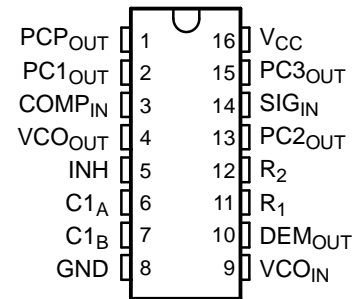


FEATURES

- **Choice of Three Phase Comparators**
 - Exclusive OR
 - Edge-Triggered J-K Flip-Flop
 - Edge-Triggered RS Flip-Flop
- **Excellent VCO Frequency Linearity**
- **VCO-Inhibit Control for ON/OFF Keying and for Low Standby Power Consumption**
- **Optimized Power-Supply Voltage Range From 3 V to 5.5 V**
- **Wide Operating Temperature Range . . . –40°C to 125°C**
- **Latch-Up Performance Exceeds 250 mA Per JESD 17**
- **ESD Protection Exceeds JESD 22**
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

D, DGV, NS, OR PW PACKAGE
(TOP VIEW)



DESCRIPTION

The SN74LV4046A is a high-speed silicon-gate CMOS device that is pin compatible with the CD4046B and the CD74HC4046. The device is specified in compliance with JEDEC Std 7.

The SN74LV4046A is a phase-locked-loop circuit that contains a linear voltage-controlled oscillator (VCO) and three different phase comparators (PC1, PC2, and PC3). A signal input and a comparator input are common to each comparator.

The signal input can be directly coupled to large voltage signals, or indirectly coupled (with a series capacitor) to small voltage signals. A self-bias input circuit keeps small voltage signals within the linear region of the input amplifiers. With a passive low-pass filter, the SN74LV4046A forms a second-order loop PLL. The excellent VCO linearity is achieved by the use of linear operational amplifier techniques.

ORDERING INFORMATION

T _A	PACKAGE	ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 125°C	SOP – NS	SN74LV4040ANS	74LV4046A
		SN74LV4040ANSR	
	SOIC – D	SN74LV4040AD	LV4046A
		SN74LV4040ADR	
	TSSOP – PW	SN74LV4040APW	LW046A
		SN74LV4040APWR	
TVSOP – DGV	SN74LV4040ADGVR	LW046A	



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SN74LV4046A HIGH-SPEED CMOS LOGIC PHASE-LOCKED LOOP WITH VCO

SCES656A—FEBRUARY 2006—REVISED FEBRUARY 2006

PIN DESCRIPTION

PIN NO.	SYMBOL	NAME AND FUNCTION
1	PCP _{OUT}	Phase comparator pulse output
2	PC1 _{OUT}	Phase comparator 1 output
3	COMP _{IN}	Comparator input
4	VCO _{OUT}	VCO output
5	INH	Inhibit input
6	C1 _A	Capacitor C1 connection A
7	C1 _B	Capacitor C1 connection B
8	GND	Ground (0 V)
9	VCO _{IN}	VCO input
10	DEM _{OUT}	Demodulator output
11	R ₁	Resistor R1 connection
12	R ₂	Resistor R2 connection
13	PC2 _{OUT}	Phase comparator 2 output
14	SIG _{IN}	Signal input
15	PC3 _{OUT}	Phase comparator 3 output
16	V _{CC}	Positive supply voltage

Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V _{CC}	DC supply voltage range	-0.5	7	V
V _I	Input voltage range	-0.5	V _{CC} + 0.5	V
V _O	Output voltage range	-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V _I < 0		-20 mA
I _{OK}	Output clamp current	V _O < 0		-50 mA
I _O	Continuous output current	V _O = 0 to V _{CC}		±35 mA
I _{CC}	DC V _{CC} or ground current			±70 mA
θ _{JA}	Package thermal impedance ⁽²⁾	D package		73
		DGV package		120
		NS package		64
		PW package		108
T _{stg}	Storage temperature range	-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The package thermal impedance is calculated in accordance with JESD 51-7.

Recommended Operating Conditions

PARAMETER		MIN	MAX	UNIT
T _A	Operating free-air temperature	-40	125	°C
V _{CC}	Supply voltage	3	5.5	V
V _I , V _O	DC input or output voltage	0	V _{CC}	V

Electrical Specifications

PARAMETER			TEST CONDITIONS		V _{CC} (V)	MIN	TYP	MAX	UNIT	
			V _I (V)	I _O (mA)						
VCO										
V _{IH}	High-level input voltage	INH			3 to 3.6	V _{CC} × 0.7			V	
					4.5 to 5.5	V _{CC} × 0.7				
V _{IL}	Low-level input voltage	INH			3 to 5.5	V _{CC} × 0.3			V	
					4.5 to 5.5	V _{CC} × 0.3				
V _{OH}	High-level output voltage	VCO _{OUT}	CMOS	V _{IL} or V _{IH}	-0.05	3 to 3.6	V _{CC} - 0.1		V	
			TTL			4.5 to 5.5	V _{CC} - 0.1			
V _{OL}	Low-level output voltage	VCO _{OUT}	CMOS	V _{IL} or V _{IH}	0.05	3 to 3.6	0.1		V	
			TTL			4.5 to 5.5	0.1			
		C1A, C1B (test purposes only)				12	4.5 to 5.5	0.55		
							4.5 to 5.5	0.65		
I _I	Input leakage current	INH, VCO _{IN}	V _{CC} or GND		5.5	±1		μA		
	R1 range ⁽¹⁾				3 to 5.5	3	50		kΩ	
	R2 range ⁽¹⁾				3 to 4.5	3	50		kΩ	
	C1 capacitance range				3 to 3.6	40	No Limit		pF	
					4.5 to 5.5	40				
	Operating voltage range	VCO _{IN}	Over the range specified for R1 for linearity ⁽²⁾		3 to 3.6	1.1	1.9		V	
						4.5 to 5.5	1.1	3.2		
Phase Comparator										
V _{IH}	DC-coupled high-level input voltage	SIG _{IN} , COMP _{IN}			3 to 3.6	V _{CC} × 0.7				
					4.5 to 5.5	V _{CC} × 0.7				
V _{IL}	DC-coupled low-level input voltage	SIG _{IN} , COMP _{IN}			3 to 3.6	V _{CC} × 0.3			V	
					4.5 to 5.5	V _{CC} × 0.3				
V _{OH}	High-level output voltage	PCP _{OUT} , PCN _{OUT}	CMOS	V _{IL} or V _{IH}	-0.05	3 to 5.5	V _{CC} - 0.1		V	
					-6	3 to 3.6	2.48			
			TTL		-12	4.5 to 5.5	3.8			
V _{OL}	Low-level output voltage	PCP _{OUT} , PCN _{OUT}	CMOS	V _{IL} or V _{IH}	0.02	3 to 3.6	0.1		V	
						4.5 to 5.5	0.1			
		TTL	4			4.5 to 5.5	0.4			
I _I	Input leakage current	SIG _{IN} , COMP _{IN}	V _{CC} or GND		3 to 3.6	±11		μA		
					4.5 to 5.5	±29				
I _{OZ}	3-state off-state current	PC2 _{OUT}	V _{IL} or V _{IH}		3 to 5.5	±5		μA		
R _I	Input resistance	SIG _{IN} , COMP _{IN}	V _I at self-bias operating point, V _I = 0.5 V		3	800		kΩ		
					4.5	250				
Demodulator										
R _S	Resistor range		R _S > 300 kΩ, Leakage current can influence V _{DEMOUT}		3 to 3.6	50	300		kΩ	
					4.5 to 5.5	50	300			
V _{OFF}	Offset voltage VCO _{IN} to V _{DEM}		V _I = V _{VCOIN} = V _{CC} /2, Values taken over R _S range		3 to 3.6	±30		mV		
					4.5 to 5.5	±20				
I _{CC}	Quiescent device current		Pins 3, 5, and 14 at V _{CC} , Pin 9 at GND, I _I at pins 3 and 14 to be excluded		5.5	50		μA		

(1) The value for R1 and R2 in parallel should exceed 2.7 kΩ.

(2) The maximum operating voltage can be as high as V_{CC} - 0.9 V; however, this may result in an increased offset voltage.

SN74LV4046A HIGH-SPEED CMOS LOGIC PHASE-LOCKED LOOP WITH VCO

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Switching Specifications

$C_L = 50$ pF, Input $t_r, t_f = 6$ ns

PARAMETER		TEST CONDITIONS	V_{CC} (V)	MIN	TYP	MAX	UNIT
Phase Comparator							
t_{PLH}, t_{PHL}	Propagation delay	SIG _{IN} , COMP _{IN} to PC1 _{OUT}	3 to 3.6			135	ns
			4.5 to 5.5			50	
t_{PLH}, t_{PHL}	Propagation delay	SIG _{IN} , COMP _{IN} to PCP _{OUT}	3 to 3.6			300	ns
			4.5 to 5.5			60	
t_{PLH}, t_{PHL}	Propagation delay	SIG _{IN} , COMP _{IN} to PC3 _{OUT}	3 to 3.6			200	ns
			4.5 to 5.5			50	
t_{THL}, t_{TLH}	Output transition time		3 to 3.6			75	ns
			4.5 to 5.5			15	
t_{PZH}, t_{PZL}	3-state output enable time	SIG _{IN} , COMP _{IN} to PC2 _{OUT}	3 to 3.6			270	ns
			4.5 to 5.5			54	
t_{PHZ}, t_{PLZ}	3-state output disable time	SIG _{IN} , COMP _{IN} to PC2 _{OUT}	3 to 3.6			320	ns
			4.5 to 5.5			65	
AC-coupled input sensitivity	(P-P) at SIG _{IN} or COMP _{IN}	$V_{I(P-P)}$	3 to 3.6		11		mV
			4.5 to 5.5		15		
VCO							
$\Delta f/\Delta T$	Frequency stability with temperature change	$V_I = VCO_{IN} = 1/2 V_{CC}$, $R_1 = 100$ k Ω , $R_2 = \infty$, $C_1 = 100$ pF	3 to 3.6		0.11		%/ $^{\circ}$ C
			4.5 to 5.5		0.11		
f_{MAX}	Maximum frequency	$C_1 = 50$ pF, $R_1 = 3.5$ k Ω , $R_2 = \infty$	3 to 3.6		24		MHz
			4.5 to 5.5		24		
			3 to 3.6		38		
			4.5 to 5.5		38		
	Center frequency (duty 50%)	$C_1 = 40$ pF, $R_1 = 3$ k Ω , $R_2 = \infty$, $VCO_{IN} = V_{CC}/2$	3 to 3.6	7	10		MHz
			4.5 to 5.5	12	17		
$\Delta f/VCO$	Frequency linearity	$C_1 = 100$ pF, $R_1 = 100$ k Ω , $R_2 = \infty$	3 to 3.6		0.4		%
			4.5 to 5.5		0.4		
	Offset frequency	$C_1 = 1$ nF, $R_2 = 220$ k Ω	3 to 3.6		400		kHz
			4.5 to 5.5		400		
Demodulator							
V_{OUT} vs f_{IN}		$C_1 = 100$ pF, $C_2 = 100$ pF, $R_1 = 100$ k Ω , $R_2 = \infty$, $R_3 = 100$ k Ω	3		8		mV/kHz
			4.5		330		

APPLICATION INFORMATION

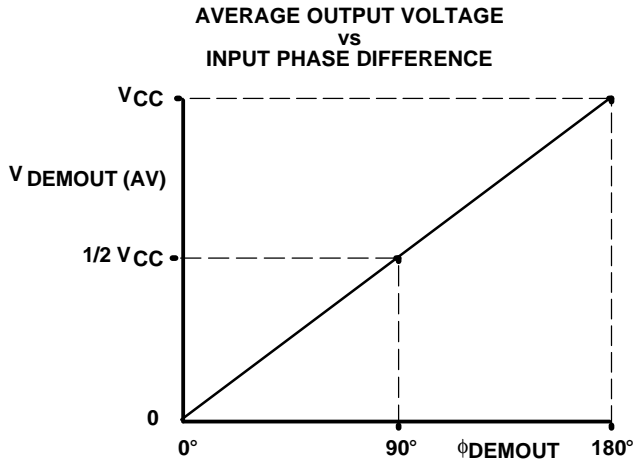


Figure 1. Phase Comparator 1:
 $V_{\text{DEMOUT}} = V_{\text{PC1OUT}} = (V_{\text{CC}}/\pi) (\text{SIG}_{\text{IN}} - \text{COMP}_{\text{IN}})$;
 $\text{DEMOUT} = (\text{SIG}_{\text{IN}} - \text{COMP}_{\text{IN}})$

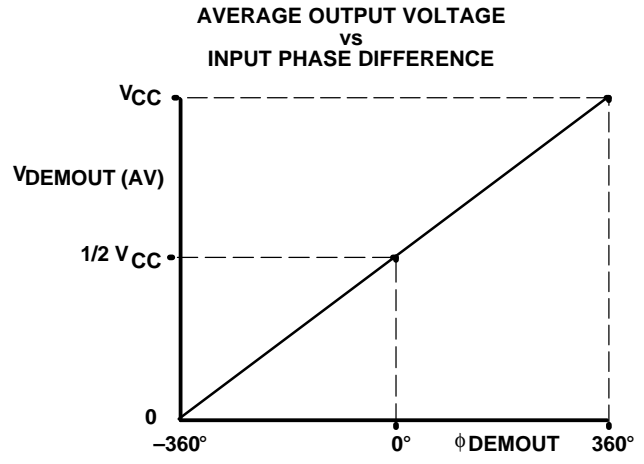


Figure 2. Phase Comparator 2:
 $V_{\text{DEMOUT}} = V_{\text{PC2OUT}} = (V_{\text{CC}}/4) (\text{SIG}_{\text{IN}} - \text{COMP}_{\text{IN}})$;
 $\text{DEMOUT} = (\text{SIG}_{\text{IN}} - \text{COMP}_{\text{IN}})$

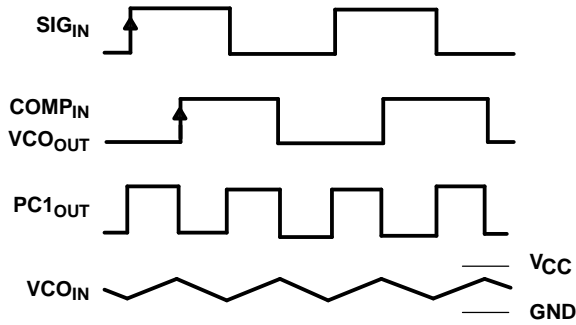


Figure 3. Typical Waveforms for PLL Using Phase Comparator 1, Loop Locked at f_o

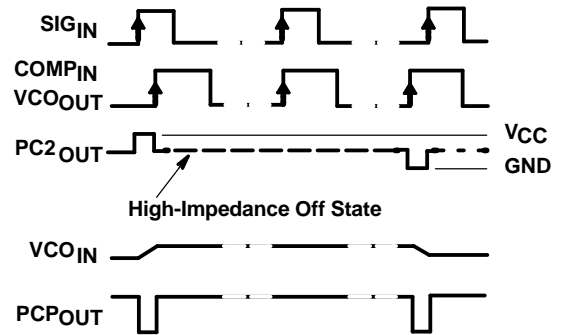


Figure 4. Typical Waveforms for PLL Using Phase Comparator 2, Loop Locked at f_o

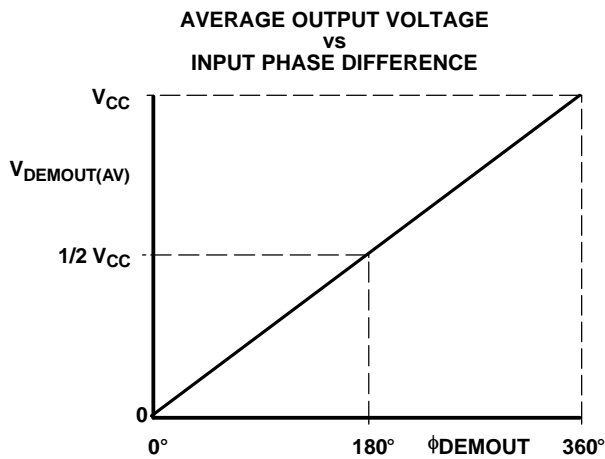


Figure 5. Phase Comparator 3:
 $V_{\text{DEMOUT}} = V_{\text{PC3OUT}} = (V_{\text{CC}}/2\pi) (\text{SIG}_{\text{IN}} - \text{COMP}_{\text{IN}})$;
 $\text{DEMOUT} = (\text{SIG}_{\text{IN}} - \text{COMP}_{\text{IN}})$

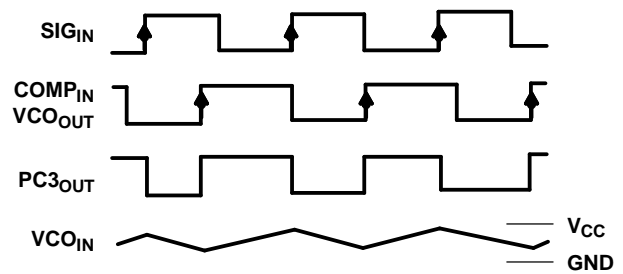


Figure 6. Typical Waveforms for PLL Using Phase Comparator 3, Loop Locked at f_o

APPLICATION INFORMATION (continued)

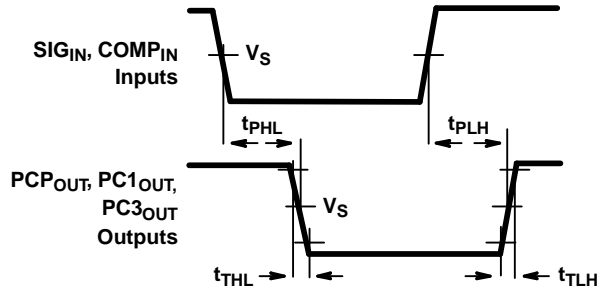


Figure 7. Input-to-Output Propagation Delays and Output Transition Times

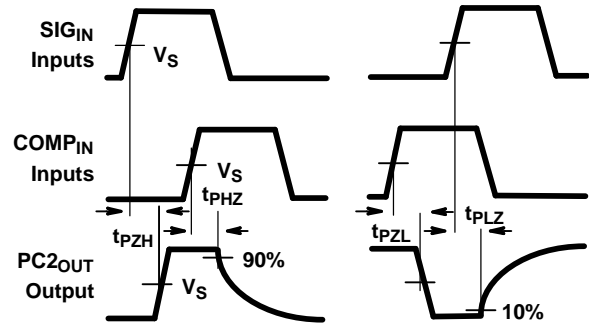


Figure 8. 3-State Enable and Disable Times for PC2_OUT

$C_{PD}^{(1)}$

CHIP SECTION	C_{PD}	UNIT
Comparator 1	120	pF
VCO	120	

- (1) R1 between 3 kΩ and 50 kΩ
R2 between 3 kΩ and 50 kΩ
R1 + R2 parallel value > 2.7 kΩ
C1 > 40 pF

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
SN74LV4046AD	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV4046ADGVR	ACTIVE	TVSOP	DGV	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV4046ADR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV4046ANS	ACTIVE	SO	NS	16	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV4046ANSR	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV4046APW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV4046APWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSELETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

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Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

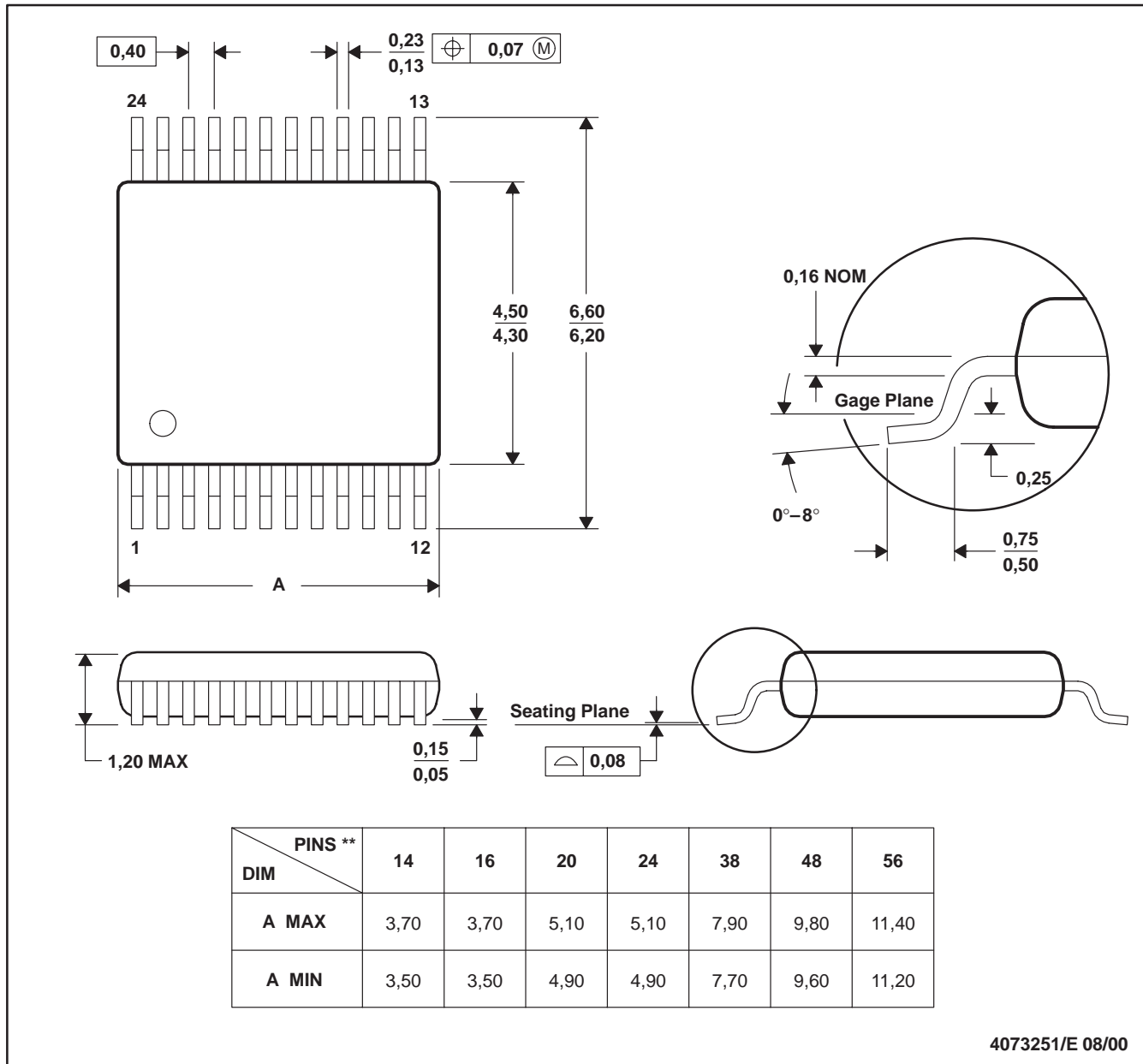
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DGV (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

24 PINS SHOWN

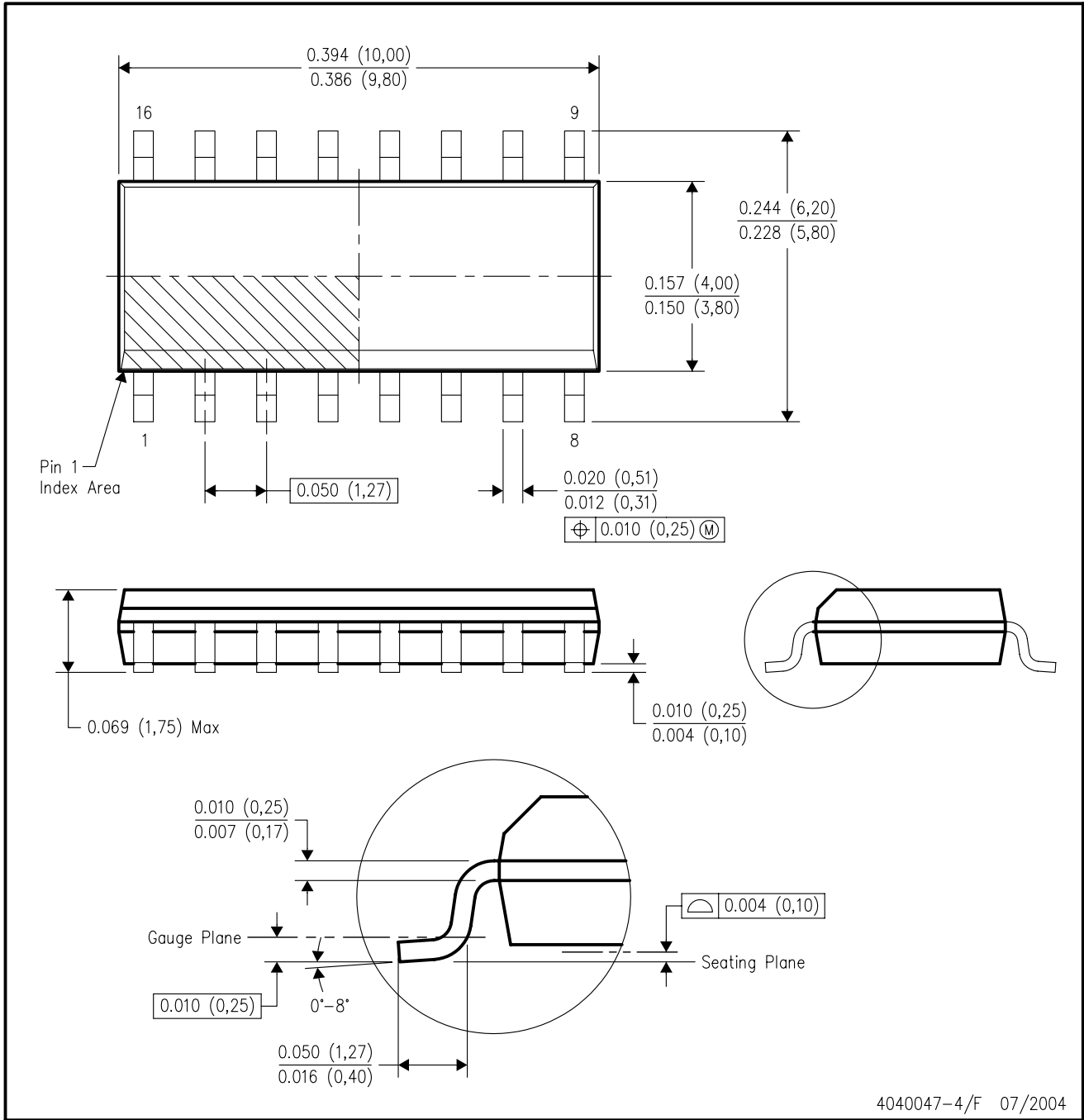


4073251/E 08/00

- NOTES: A. All linear dimensions are in millimeters.
 B. This drawing is subject to change without notice.
 C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
 D. Falls within JEDEC: 24/48 Pins – MO-153
 14/16/20/56 Pins – MO-194

D (R-PDSO-G16)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
 - D. Falls within JEDEC MS-012 variation AC.

MECHANICAL DATA

NS (R-PDSO-G)**

PLASTIC SMALL-OUTLINE PACKAGE

14-PINS SHOWN

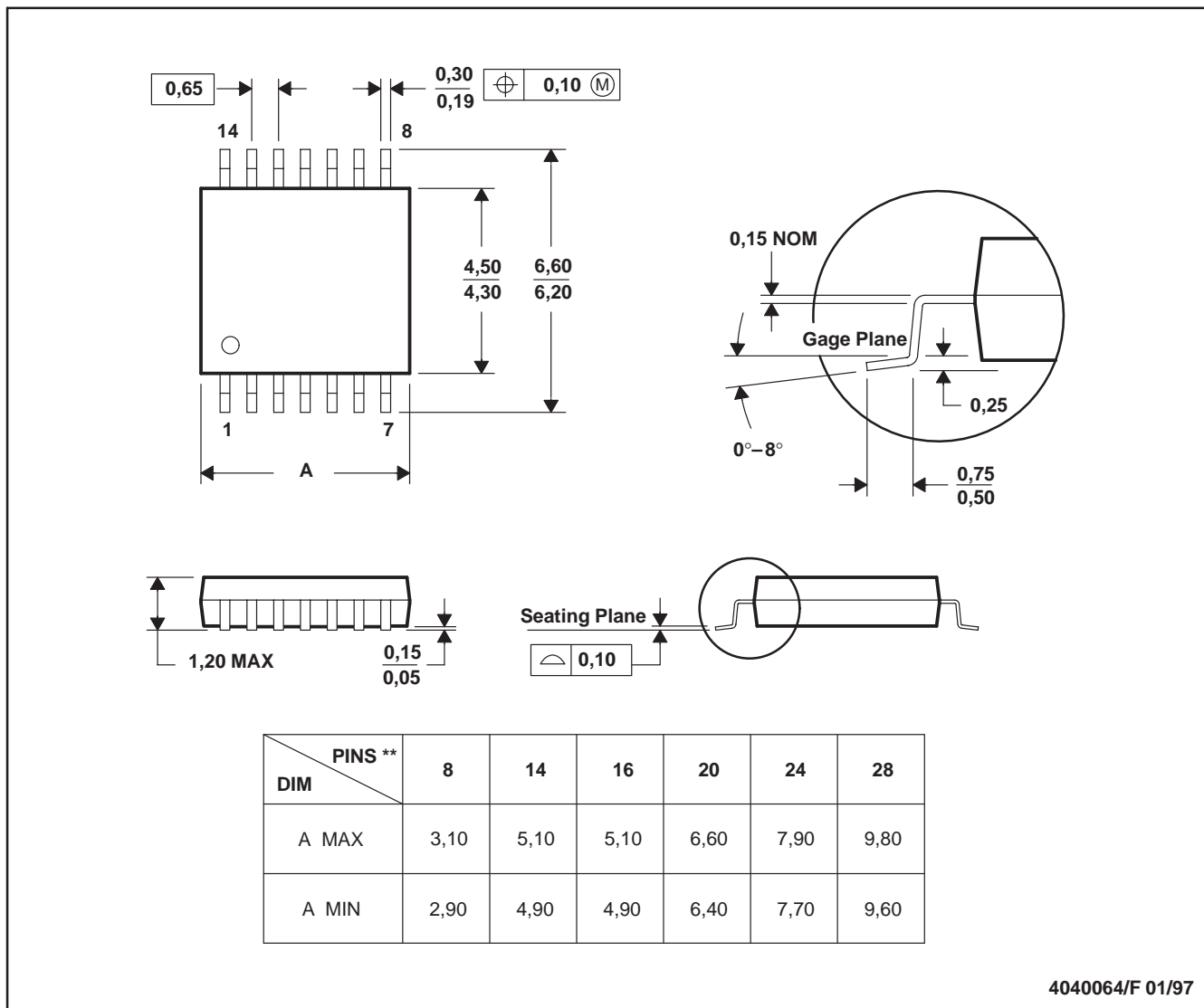


- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.

PW (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

14 PINS SHOWN



4040064/F 01/97

- NOTES: A. All linear dimensions are in millimeters.
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 D. Falls within JEDEC MO-153

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